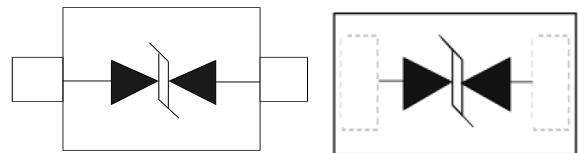


## Description

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one data line from the damage caused by ESD.



## Features

- Bidirectional ESD protection of one line
- Ultra low diode capacitance:  $C_d = 2.9 \text{ pF}$
- IEC 61000-4-2; level 4 (ESD)
- Ultra low leakage current:  $I_{RM} = 5 \text{ nA}$
- ESD protection of up to 10 kV

## Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- 10/100/1000 Ethernet
- Local Area Network (LAN) equipment
- Communication systems
- Portable electronics
- Subscriber Identity Module (SIM) card protection
- FireWire
- High-speed data lines

## Quick reference data

$T_{amb} = 25 \text{ }^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per diode</b>						
$V_{RWM}$	reverse standoff voltage		-	-	5	V
$C_d$	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	-	2.9	3.5	pF

## Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
<b>Per device</b>					
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-65	+150	°C
$T_{stg}$	storage temperature		-65	+150	°C

## ESD maximum ratings

Symbol	Parameter	Conditions		Min	Max	Unit
<b>Per diode</b>						
$V_{ESD}$	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2]	-	10	kV
		MIL-STD-883 (human body model)		-	8	kV

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to pin 2.

## ESD standards compliance

Standard	Conditions
<b>Per diode</b>	
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

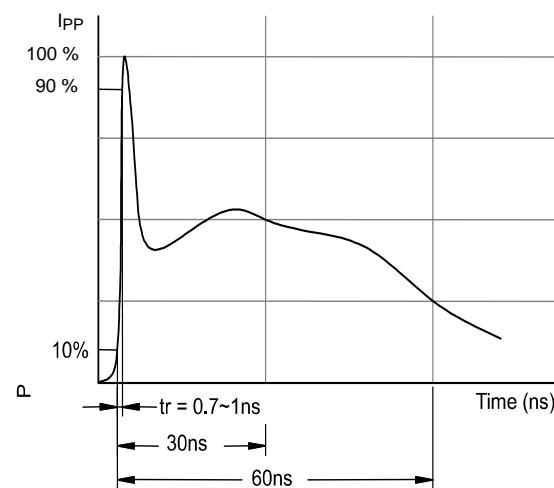
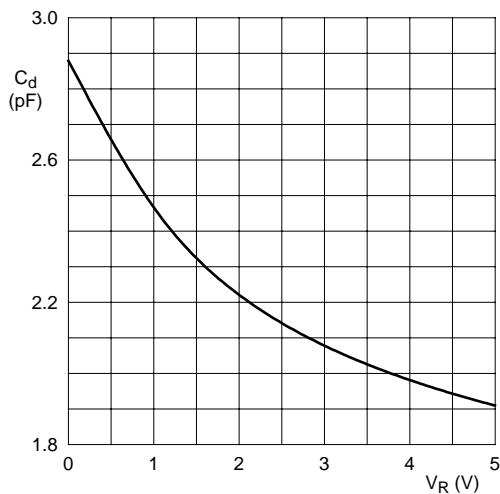


Fig 1. ESD pulse waveform according to IEC 61000-4-2

## Characteristics

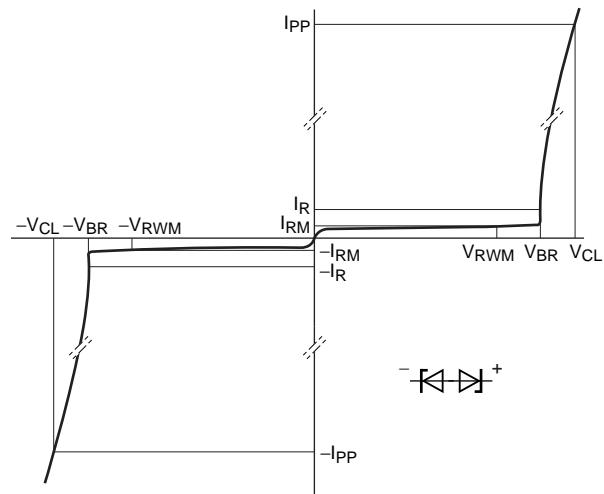
$T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per diode</b>						
$V_{RWM}$	reverse standoff voltage		-	-	5	V
$I_{RM}$	reverse leakage current	$V_{RWM} = 5\text{ V}$	-	5	100	nA
$V_{BR}$	breakdown voltage	$I_R = 5\text{ mA}$	5.5	7	9.5	V
$C_d$	diode capacitance	$f = 1\text{ MHz}$				
		$V_R = 0\text{ V}$	-	2.9	3.5	pF
		$V_R = 5\text{ V}$	-	1.9	-	pF
$r_{dif}$	differential resistance	$I_R = 1\text{ mA}$	-	-	100	$\Omega$

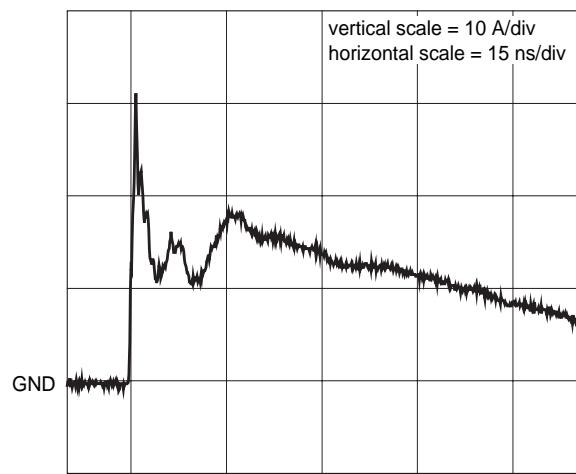


$f = 1\text{ MHz}; T_{amb} = 25^{\circ}\text{C}$

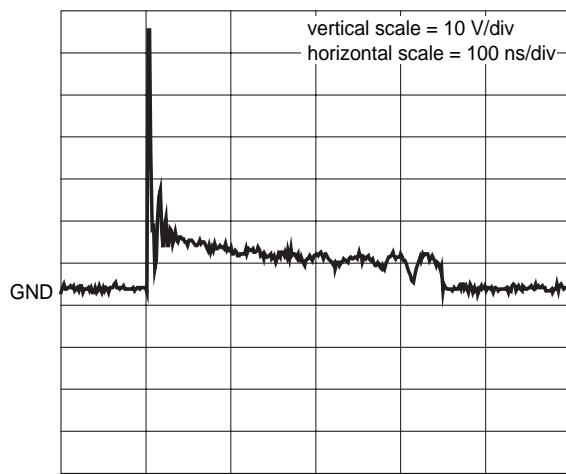
**Fig 2. Diode capacitance as a function of reverse voltage; typical values**



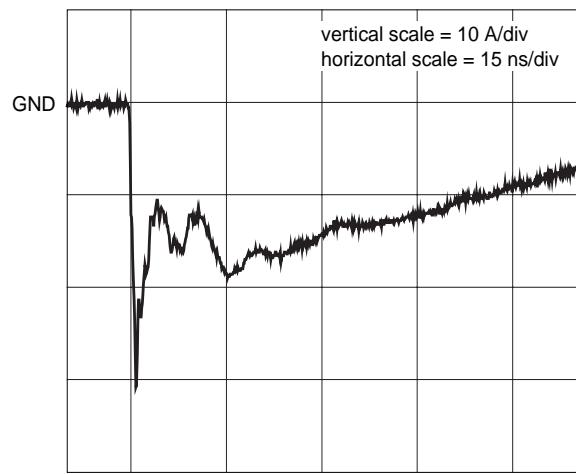
**Fig 3. V-I characteristics for a bidirectional ESD protection diode**



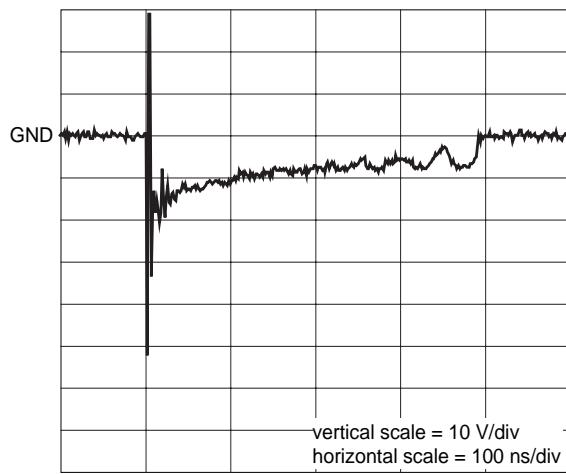
unclamped +8 kV ESD pulse waveform  
(IEC 61000-4-2 network)



clamped +8 kV ESD pulse waveform  
(IEC 61000-4-2 network) pin 1 to 2



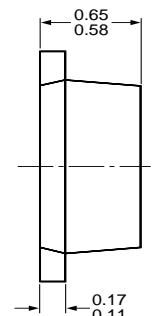
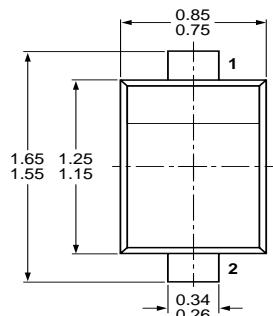
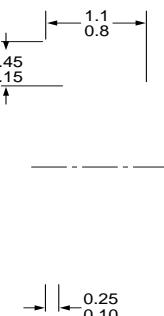
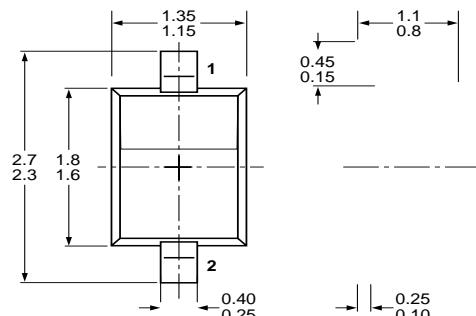
unclamped -8 kV ESD pulse waveform  
(IEC 61000-4-2 network)



clamped -8 kV ESD pulse waveform  
(IEC 61000-4-2 network) pin 1 to 2

**Fig 4. ESD clamping test setup and waveforms**

## SOD-323/SOD-523/SOD-882 PACKAGE OUTLINE DIMENSIONS

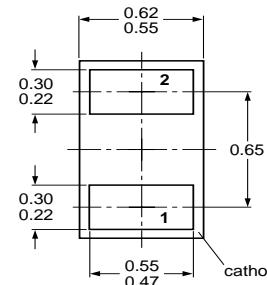


Dimensions in mm 03-12-17

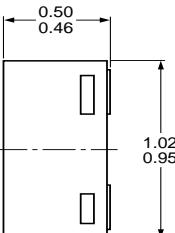
Dimensions in mm

Dimensions in mm 02-12-13

PESD5V0L1UA (SOD323)



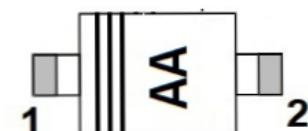
Dimensions in mm



Dimensions in mm 03-04-17

PESD5V0L1UB (SOD523)

PESD5V0L1UL (SOD882)



## Marking



## Ordering information

Order Code	Marking code	Package	Baseqty	Deliverymode
UMW PESD5V0U1BA	AA	SOD-323	3000	Tape and reel
UMW PESD5V0U1BB	B3	SOD-523	3000	Tape and reel
UMW PESD5V0U1BL	VB	SOD-882	10000	Tape and reel